







TPS62A06, TPS62A06A SLUSET0A - APRIL 2023 - REVISED JUNE 2023

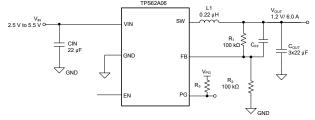
# TPS62A06x, 6-A, High-Efficiency, Synchronous Buck Converter in a SOT563 Package

### 1 Features

- 2.5-V to 5.5-V input voltage range
- 0.6-V to V<sub>IN</sub> adjustable output voltage range
- 15-mΩ / 10-mΩ low  $R_{DSON}$  switches (6 A)
- 25-µA quiescent current
- 1% feedback accuracy (0°C to 125°C)
- 100% mode operation
- 2.2-MHz switching frequency
- Power save mode or FPWM option available
- Power-good output pin
- Short-circuit protection (HICCUP)
- Internal soft start-up
- Output discharge
- Thermal shutdown protection
- Available in a 1.6-mm × 1.6-mm SOT563 package
- Pin-to-pin compatible with the TLV62585

# 2 Applications

- Multi-function printer
- Set top box
- TV applications
- IP network camera
- Wireless router, solid state drive
- **Battery-powered applications**
- General purpose point-of-load supply



Typical Application

# 3 Description

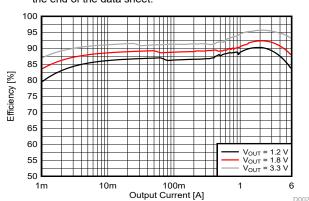
The TPS62A06 family of devices are synchronous, step-down, buck, DC/DC converters optimized for high efficiency and compact solution size. The device integrates switches capable of delivering an output current up to 6 A. At medium to heavy loads, the device operates in pulse width modulation (PWM) mode with 2.2-MHz switching frequency. At light load, the device automatically enters power save mode (PSM) to maintain high efficiency over the entire load current range. The TPS62A06A variants of this device family operate in forced PWM across the whole load current range.

The TPS62A06 provides an adjustable output voltage through an external resistor divider. An internal softstart circuit limits the inrush current during start-up. Other features like overcurrent protection, thermal shutdown protection, and power good are built-in. The device is available in a SOT563 package.

#### **Device Information**

PART NUMBER	MODE	PACKAGE <sup>(1)</sup>	BODY SIZE (NOM)
TPS62A06	PSM, PWM	DRL	1.60 mm × 1.60 mm
TPS62A06A	FPWM	(SOT563, 6)	1.00 11111 ~ 1.00 111111

For all available packages, see the orderable addendum at the end of the data sheet.



Efficiency Versus Output Current at 5 VIN



# **Table of Contents**

1 Features	1 8.4 Device Functional Modes	8
2 Applications		
3 Description		0
4 Revision History	2 9.2 Typical Application1	0
5 Device Comparison Table		
6 Pin Configuration and Functions	3 9.4 Layout1	4
7 Specifications		
7.1 Absolute Maximum Ratings		
7.2 ESD Ratings	4 10.2 Documentation Support	5
7.3 Recommended Operating Conditions		5
7.4 Thermal Information	4 10.4 Support Resources1	5
7.5 Electrical Characteristics	5 10.5 Trademarks1	5
7.6 Typical Characteristics		5
8 Detailed Description	7 10.7 Glossary1	5
8.1 Overview		
8.2 Functional Block Diagram		5
8.3 Feature Description		

# **4 Revision History**

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

С	hanges from Revision * (April 2023) to Revision A (June 2023)	Page
•	Changed document status from Advance Information to Production Data	1



# **5 Device Comparison Table**

DEVICE NUMBER	OUTPUT CURRENT	OPERATION MODE
TPS62A06	6 A	PSM/ PWM
TPS62A06A	6 A	FPWM

# **6 Pin Configuration and Functions**

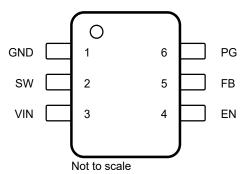


Figure 6-1. 6-Pin DRL SOT563 Package (Top View)

Table 6-1. Pin Functions

PI	N	I/O <sup>(1)</sup>	DESCRIPTION
NAME	NO.	1/0	DESCRIPTION
EN	4	ı	Device enable logic input. Logic high enables the device, logic low disables the device and turns the device into shutdown. Do not leave the pin floating.
FB	5	I	Feedback pin for the internal control loop. Connect this pin to an external feedback divider.
GND	1	G	Ground pin
PG	6	0	Power-good open-drain output pin. The pullup resistor cannot be connected to any voltage higher than 5.5 V. If unused, leave the pin open or connect to GND.
SW	2	0	Switch pin connected to the internal FET switches and inductor terminal. Connect the inductor of the output filter to this pin.
VIN	3	I	Power supply voltage pin

(1) I = Input, O = Output, G = Ground



# 7 Specifications

# 7.1 Absolute Maximum Ratings

Over operating free-air temperature range (unless otherwise noted)(1)

		MIN	MAX	UNIT
	VIN, EN, PG	-0.3	6	V
Pin voltage <sup>(2)</sup>	SW, DC	-0.3	V <sub>IN</sub> + 0.3	V
Fill voltage	SW, transient < 10 ns	-3.0	10	V
	FB	-0.3	3	V
T <sub>J</sub>	Operating junction temperature	-40	150	°C
T <sub>stg</sub>	Storage temperature	-55	150	°C

<sup>(1)</sup> Operation outside the Absolute Maximum Ratings may cause permanent device damage. Absolute Maximum Ratings do not imply functional operation of the device at these or any other conditions beyond those listed under Recommended Operating Conditions. If used outside the Recommended Operating Conditions but within the Absolute Maximum Ratings, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.

(2) All voltage values are with respect to the network ground terminal.

# 7.2 ESD Ratings

			VALUE	UNIT
V		Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup>	±2000	V
V <sub>(ESD)</sub>	Electrostatic discharge	Charged-device model (CDM), per ANSI/ESDA/JEDEC JS-002 <sup>(2)</sup>	±500	V

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

# 7.3 Recommended Operating Conditions

Over operating junction temperature range (unless otherwise noted)

			MIN	NOM	MAX	UNIT
V <sub>IN</sub>	Input supply voltage range		2.5		5.5	V
V <sub>OUT</sub>	Output voltage range		0.6		V <sub>IN</sub>	V
L	Effective inductance			0.22		μH
C <sub>OUT</sub>	Effective output capacitance	V <sub>OUT</sub> < 1.2 V		120		μF
C <sub>OUT</sub>	Effective output capacitance	1.2 V <= V <sub>OUT</sub> < 1.8 V		45		μF
C <sub>OUT</sub>	Effective output capacitance	V <sub>OUT</sub> => 1.8 V		45		μF
I <sub>OUT</sub>	Output current range	TPS62A06	0		6	Α
I <sub>PG</sub>	Power Good input current capability		0		1	mA
T <sub>J</sub>	Operating junction temperature		-40		125	°C

# 7.4 Thermal Information

		TPS62A06x	TPS62A06EVM-248	
THERMAL METRIC(1)		DRL	EVM	UNIT
		6 PINS	6 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	137.5	74.5	°C/W
R <sub>0JC(top)</sub>	Junction-to-case (top) thermal resistance	60.2	-	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	22.0	-	°C/W
ΨЈТ	Junction-to-top characterization parameter	1.4	1.2	°C/W
ΨЈВ	Junction-to-board characterization parameter	21.6	33.7	°C/W

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.



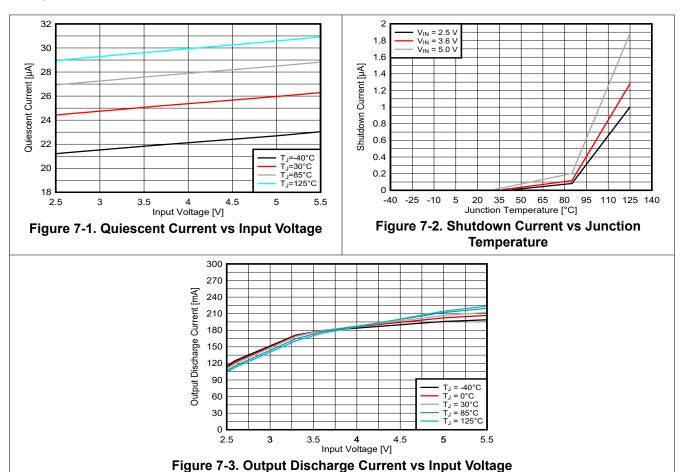
# 7.5 Electrical Characteristics

 $T_J$  = -40°C to +125°C,  $V_{IN}$  = 2.5 V to 5.5 V. Typical values are at  $T_J$  = 25°C and  $V_{IN}$  = 5 V (unless otherwise noted)

	TEST CONDITIONS	`			UNIT
TANAMETER	TEST SONDITIONS	Will C	• • • •	MAX	Olti
VINI guissaant aumant	Non quitables // - High // - 610 m/		26	1	
				4	μA
VIN snutdown supply current	$I_J = -40^{\circ}C$ to 85°C, $V_{EN} = Low$		0.01	4	μA
I	T			1	
					V
VIN UVLO falling threshold	V <sub>IN</sub> falling	2.2	2.3	2.4	V
EN voltage rising threshold	EN rising, enable switching	1.2			V
EN voltage falling threshold	EN falling, disable switching			0.4	V
EN Input leakage current	V <sub>EN</sub> = 5 V			100	nA
DLTAGE					
FB voltage	T <sub>J</sub> = 0°C to 125°C, PWM mode	594	600	606	mV
FB voltage	PWM mode	591	600	609	mV
FB input leakage current	V <sub>FB</sub> = 0.6 V			100	nA
EQUENCY					
Switching frequency, FPWM operation	V <sub>IN</sub> = 5 V, V <sub>OUT</sub> = 1.8 V		2200		kHz
Internal fixed soft-start time	From EN = High to V <sub>FB</sub> = 0.56 V		0.5	1	ms
High-side MOSFET on-resistance	TPS62A06, V <sub>IN</sub> = 5 V		15		mΩ
Low-side MOSFET on-resistance			10		mΩ
PROTECTION					
High-side peak current limit	TPS62A06	8.2	10		Α
	TPS62A06		9.1		Α
,					
Power Good threshold	PG low. FB falling		93.5		%
					%
	l c mg., c c mang				μs
					μs
PG pin Leakage current when open drain	V <sub>PG</sub> = 5 V			100	nA
<u> </u>	I <sub>PC</sub> = 1 mA			400	mV
ARGE	1.0				
	V <sub>IN</sub> = 3 V, V <sub>OUT</sub> = 2.0 V		150		mA
	- IIN				
	Temperature rising		170		°C
	Tomportation forming				°C
	EN voltage falling threshold EN Input leakage current  DLTAGE  FB voltage FB voltage FB input leakage current  EQUENCY  Switching frequency, FPWM operation  Internal fixed soft-start time  High-side MOSFET on-resistance Low-side MOSFET on-resistance  Low-side MOSFET on-resistance  TPROTECTION  High-side peak current limit Low-side valley current limit  Power Good threshold Power Good threshold PG delay falling PG delay rising PG pin Leakage current when open drain output is high PG pin output low-level voltage	VIN quiescent current   Non-switching, V <sub>EN</sub> = High, V <sub>FB</sub> = 610 mV     VIN shutdown supply current   T <sub>J</sub> = −40°C to 85°C, V <sub>EN</sub> = Low     VIN UVLO rising threshold   V <sub>IN</sub> rising     VIN UVLO falling threshold   V <sub>IN</sub> falling     EN voltage rising threshold   EN falling, disable switching     EN voltage falling threshold   EN falling, disable switching     EN lnput leakage current   V <sub>EN</sub> = 5 V     DITAGE     FB voltage   T <sub>J</sub> = 0°C to 125°C, PWM mode     FB voltage   PWM mode     FB input leakage current   V <sub>FB</sub> = 0.6 V     EQUENCY     Switching frequency, FPWM operation   V <sub>IN</sub> = 5 V, V <sub>OUT</sub> = 1.8 V     Internal fixed soft-start time   From EN = High to V <sub>FB</sub> = 0.56 V     High-side MOSFET on-resistance   TPS62A06, V <sub>IN</sub> = 5 V     Low-side MOSFET on-resistance   TPS62A06   TPS62A06     Low-side valley current limit   TPS62A06     Low-side valley current limit   TPS62A06     Power Good threshold   PG low, FB falling     PG delay falling   PG delay falling     PG delay falling   PG delay rising     PG pin Leakage current when open drain output is high     PG pin output low-level voltage   I <sub>PG</sub> = 1 mA     ARGE   Output discharge current on SW pin   V <sub>IN</sub> = 3 V, V <sub>OUT</sub> = 2.0 V     TDOWN     Thermal shutdown threshold   Temperature rising	VIN quiescent current   Non-switching, V <sub>EN</sub> = High, V <sub>FB</sub> = 610 mV     VIN shutdown supply current   T <sub>J</sub> = -40°C to 85°C, V <sub>EN</sub> = Low     VIN UVLO rising threshold   V <sub>IN</sub> rising   2.3     VIN UVLO falling threshold   V <sub>IN</sub> falling   2.2     EN voltage rising threshold   EN rising, enable switching   1.2     EN voltage falling threshold   EN falling, disable switching   V <sub>EN</sub> = 5 V     DITAGE	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	VIN quiescent current



# 7.6 Typical Characteristics



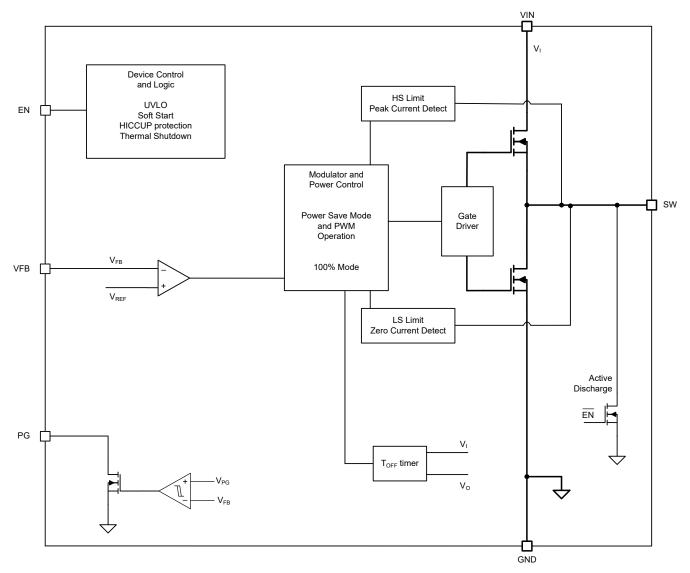


# **8 Detailed Description**

# 8.1 Overview

The TPS62A0x is a high-efficiency, synchronous step-down converter. The device operates with an adaptive off time with a peak current control scheme. The device operates typically at 2.2-MHz frequency pulse width modulation (PWM) at moderate to heavy load currents. Based on the  $V_{IN}/V_{OUT}$  ratio, a simple circuit sets the required off time for the low-side MOSFET. This action makes the switching frequency relatively constant regardless of the variation of the input voltage, output voltage, and load current.

# 8.2 Functional Block Diagram



### 8.3 Feature Description

#### 8.3.1 Power Save Mode

The device automatically enters power save mode to improve efficiency at light load when the inductor current becomes discontinuous. In power save mode, the converter reduces the switching frequency and minimizes current consumption. In power save mode, the output voltage rises slightly above the nominal output voltage. This effect is minimized by increasing the output capacitor or adding a feedforward capacitor.

### 8.3.2 100% Duty Cycle Low Dropout Operation

The device offers low input-to-output voltage difference by entering 100% duty cycle mode. In this mode, the high-side MOSFET switch is constantly turned on and the low-side MOSFET is switched off. The minimum input voltage to maintain output regulation, depending on the load current and output voltage, is calculated as:

$$V_{IN(MIN)} = V_{OUT} + I_{OUT} \times R_{DS(ON)} + R_{L}$$
(1)

#### where

- R<sub>DS(ON)</sub> = High-side FET on-resistance
- R<sub>L</sub> = Inductor ohmic resistance (DCR)

#### 8.3.3 Soft Start

After enabling the device, internal soft start-up circuitry ramps up the output voltage, which reaches the nominal output voltage during start-up time, avoiding excessive inrush current and creating a smooth output voltage rise slope. soft start-up circuitry also prevents excessive voltage drops of primary cells and rechargeable batteries with high internal impedance.

The TPS62A0x is able to start into a pre-biased output capacitor. The converter starts with the applied bias voltage and ramps the output voltage to its nominal value.

### 8.3.4 Switch Current Limit and Short-Circuit Protection (HICCUP)

The switch current limit prevents the device from high inductor current and from drawing excessive current from the battery or input voltage rail. Excessive current can occur with a shorted or saturated inductor or an overload or shorted output circuit condition. If the inductor current reaches the threshold I<sub>LIM</sub>, the high-side MOSFET is turned off and the low-side MOSFET is turned on to ramp down the inductor current with an adaptive off time.

When this switch current limit is triggered 32 times, the device reduces the current limit for further 32 cycles and then stops switching to protect the output. The device then automatically starts a new start-up after a typical delay time of 500 µs has passed. This action is named HICCUP short-circuit protection. The device repeats this mode until the high load condition disappears. HICCUP protection is also enabled during the start-up.

#### 8.3.5 Undervoltage Lockout

To avoid misoperation of the device at low input voltages, an undervoltage lockout (UVLO) is implemented, which shuts down the device at voltages lower than  $V_{UVLO}$  with a hysteresis of 130 mV.

### 8.3.6 Thermal Shutdown

The device goes into thermal shutdown and stops switching when the junction temperature exceeds T<sub>JSD</sub>. When the device temperature falls below the threshold by 20°C, the device returns to normal operation automatically.

# 8.4 Device Functional Modes

#### 8.4.1 Enable and Disable

The device is enabled by setting the EN input to a logic High. Accordingly, a logic Low disables the device. If the device is enabled, the internal power stage starts switching and regulates the output voltage to the set point voltage. The EN input must be terminated and must not be left floating.

#### 8.4.2 Power Good

The TPS62A06x has a built-in power-good (PG) feature to indicate whether the output voltage has reached its target and the device is ready. The PG signal can be used for start-up sequencing of multiple rails. The PG pin is an open-drain output that requires a pullup resistor to any voltage up to the recommended input voltage level. PG is low when the device is turned off due to EN, UVLO (undervoltage lockout), or thermal shutdown. VIN must remain present for the PG pin to stay low.

If the power-good output is not used, TI recommends to tie to GND or leave open.



**Table 8-1. Power-Good indicator Functional Table** 

	LOGIC SIGNALS					
V <sub>I</sub>	EN PIN	THERMAL SHUTDOWN	v <sub>o</sub>	PG STATUS		
llion.			V <sub>O</sub> on target	High Impedance		
	V <sub>1</sub> > UVLO  HIGH  UVLO < V <sub>1</sub> < 1.8 V	NO	V <sub>O</sub> < target	LOW		
V <sub>I</sub> > UVLO			YES	LOW		
		YES	х	LOW		
		х	Х	LOW		
V <sub>I</sub> < 1.8 V	х	x	х	Undefined		

The PG indicator features a de-glitch to avoid the signal indicating glitches or transient responses from the loop sketch the behavior.

# 9 Application and Implementation

#### **Note**

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

# 9.1 Application Information

The following section discusses the design of the external components to complete the power supply design for several input and output voltage options by using typical applications as a reference.

# 9.2 Typical Application

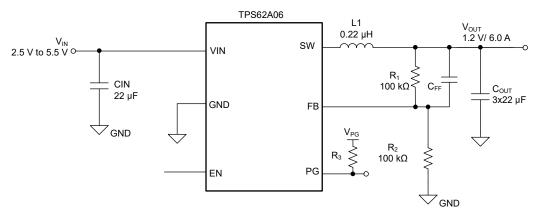


Figure 9-1. TPS62A06 Typical Application Circuit

# 9.2.1 Design Requirements

For this design example, use the parameters listed in Table 9-1 as the input parameters

**Table 9-1. Design Parameters** 

		<u> </u>
DESIGN PARAMETER		EXAMPLE VALUE
	Input voltage	2.5 V to 5.5 V
	Output voltage	1.2 V
	Maximum output current	6.0 A

Table 9-2 lists the components used for the example.

**Table 9-2. List of Components** 

REFERENCE	DESCRIPTION	MANUFACTURER <sup>(1)</sup>						
C1	22 μF, Ceramic Capacitor, 10 V, X7R, size 0805, GRM21BZ71A226KE15L	Murata						
C2, C3, C4	22 μF, Ceramic Capacitor, 10 V, X7R, size 0805, GRM21BZ71A226KE15L	Murata						
L1	0.22 μH, Power Inductor, XGL4015-221MEC	Coilcraft						
R1, R2	Chip resistor, 1%, size 0603	Std.						
C5	Optional, 120 pF if needed	Std.						

<sup>(1)</sup> See the *Third-Party Products Disclaimer*.



### 9.2.2 Detailed Design Procedure

# 9.2.2.1 Setting the Output Voltage

The output voltage is set by an external resistor divider according to Equation 2. To keep the feedback (FB) net robust from noise, set R2 equal to or lower than 100 k $\Omega$  to have at least 6  $\mu$ A of current in the voltage divider. Lower values of FB resistors achieve better noise immunity, and lower light load efficiency, as explained in the Design Considerations for a Resistive Feedback Divider in a DC/DC Converter technical brief.

$$R1 = R2 \times \left(\frac{V_{OUT}}{V_{FB}} - 1\right) = R2 \times \left(\frac{V_{OUT}}{0.6 V} - 1\right)$$
(2)

# 9.2.2.2 Feedforward Capacitor

TI recommends a feedforward capacitor  $C_{FF}$  in parallel with  $R_1$  to improve the load transient performance and reduce the output ripple voltage in PSM. The recommended value for  $C_{FF}$  is 120 pF.

### 9.2.2.3 Output Filter Design

The inductor and output capacitor together provide a low-pass filter. To simplify this process, Table 9-3 outlines possible inductor and capacitor value combinations. Checked cells represent combinations that are proven for stability by simulation and lab test. Check further combinations for each individual application.

**Table 9-3. Matrix of Output Capacitor and Inductor Combinations** 

V IVI	L F.,LU7(1)		C <sub>OUT</sub> [μF] <sup>(2)</sup>	
V <sub>OUT</sub> [V]	L [µH] <sup>(1)</sup>	3 × 22	2 × 47	3 × 47
0.6 ≤ V <sub>OUT</sub> < 1.2	0.22		++(3)	++
1.2 ≤ V <sub>OUT</sub> < 1.8	0.22	++(3)	+	+
1.8 ≤ V <sub>OUT</sub>	0.22	++(3)	+	+

- Inductor tolerance and current de-rating is anticipated. The effective inductance can vary by +20% and -30%.
- (2) Capacitance tolerance and bias voltage de-rating is anticipated. The effective capacitance can vary by +20% and -50%.
- (3) This LC combination is the standard value and recommended for most applications.

#### 9.2.2.4 Input and Output Capacitor Selection

The architecture of the TPS62A0x allows use of tiny ceramic-type output capacitors with low equivalent series resistance (ESR). These capacitors provide low output voltage ripple and are thus recommended. To keep resistance up to high frequencies and to achieve narrow capacitance variation with temperature, TI recommends to use X7R or X5R dielectric.

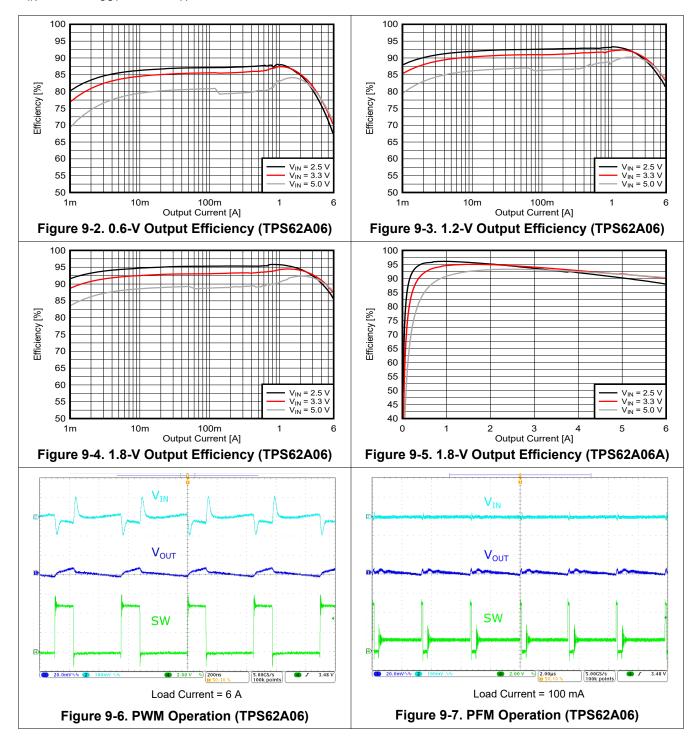
The input capacitor is the low impedance energy source for the converter that helps provide stable operation. TI recommends a low-ESR multilayer ceramic capacitor for best filtering. For most applications, a 10-µF input capacitor is sufficient; a larger value reduces input voltage ripple.

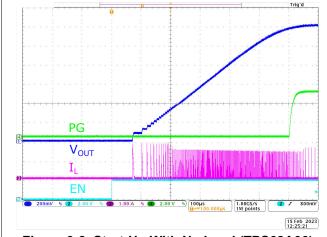
The recommended typical output capacitor value for 1.2-V output typical application is 45  $\mu$ F of effective capacitance. This capacitance can vary over a wide range, as outlined in Table 9-3.



# 9.2.3 Application Curves

 $V_{IN}$  = 5.0 V,  $V_{OUT}$  = 1.2 V,  $T_A$  = 25°C, BOM = Table 9-2 unless otherwise noted.





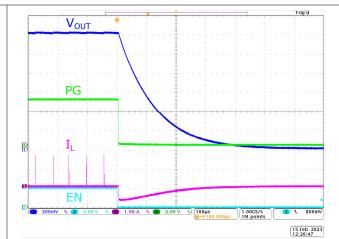
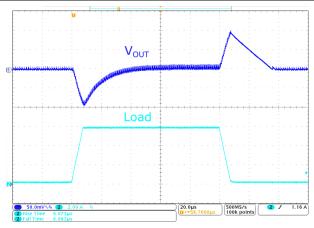
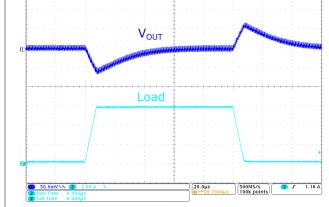


Figure 9-8. Start-Up With No Load (TPS62A06)

Figure 9-9. Shutdown With No Load (TPS62A06)



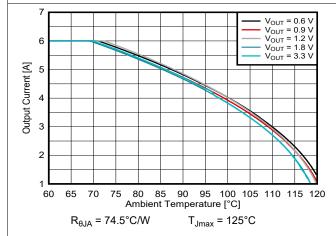


Load Step: 0.1 A to 6 A, 1 A/µs

Load Step: 0.1 A to 6 A, 1 A/µs

Figure 9-10. Load Transient Response (TPS62A06)

Figure 9-11. Load Transient Response (TPS62A06A)



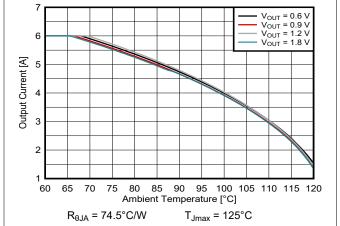


Figure 9-12. Safe Operating Area Based On EVM,  $V_{IN} = 5.0 \text{ V}$ , TPS62A06DRL

Figure 9-13. Safe Operating Area Based On EVM, V<sub>IN</sub> = 3.3 V, TPS62A06DRL

# 9.3 Power Supply Recommendations

The device is designed to operate from an input voltage supply range from 2.5 V to 5.5 V. Ensure that the input power supply has a sufficient current rating for the application.

# 9.4 Layout

# 9.4.1 Layout Guidelines

The printed-circuit-board (PCB) layout is an important step to maintain the high performance of the TPS62A0x device.

- Place the input and output capacitors and the inductor as close as possible to the IC. This action keeps
  the power traces short. Routing these power traces direct and wide results in low trace resistance and low
  parasitic inductance.
- Connect the low side of the input and output capacitors properly to the GND pin to avoid a ground potential shift.
- Take special care to avoid noise being induced. The sense traces connected to FB is a signal trace. Keep these traces away from SW nodes.
- Use common ground. GND layers can be used for shielding.

See Figure 9-14 for the recommended PCB layout.

# 9.4.2 Layout Example

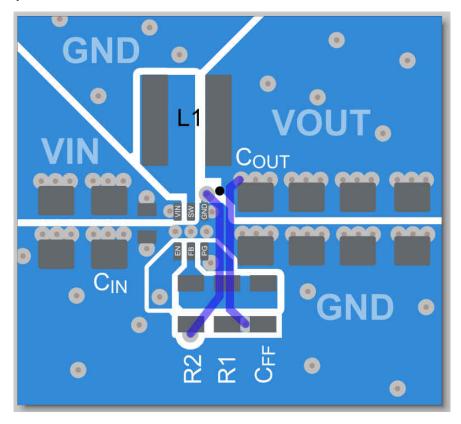


Figure 9-14. TPS62A06x PCB Layout Recommendation



# 10 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

# 10.1 Device Support

### 10.1.1 Third-Party Products Disclaimer

TI'S PUBLICATION OF INFORMATION REGARDING THIRD-PARTY PRODUCTS OR SERVICES DOES NOT CONSTITUTE AN ENDORSEMENT REGARDING THE SUITABILITY OF SUCH PRODUCTS OR SERVICES OR A WARRANTY, REPRESENTATION OR ENDORSEMENT OF SUCH PRODUCTS OR SERVICES, EITHER ALONE OR IN COMBINATION WITH ANY TI PRODUCT OR SERVICE.

# **10.2 Documentation Support**

## 10.2.1 Related Documentation

Texas Instruments, Design Considerations for a Resistive Feedback Divider in a DC/DC Converter technical brief

# 10.3 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

# 10.4 Support Resources

TI E2E<sup>™</sup> support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

#### 10.5 Trademarks

TI E2E™ is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

### 10.6 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

#### 10.7 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

# 11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

9-Nov-2025

www.ti.com

### PACKAGING INFORMATION

Orderable part number	Status	Material type	Package   Pins	Package qty   Carrier	RoHS	Lead finish/	MSL rating/	Op temp (°C)	Part marking
	(1)	(2)			(3)	Ball material	Peak reflow		(6)
						(4)	(5)		
TPS62A06ADRLR	Active	Production	SOT-5X3 (DRL)   6	4000   LARGE T&R	Yes	Call TI   Sn	Level-1-260C-UNLIM	-40 to 125	1MH
TPS62A06ADRLR.A	Active	Production	SOT-5X3 (DRL)   6	4000   LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	1MH
TPS62A06DRLR	Active	Production	SOT-5X3 (DRL)   6	4000   LARGE T&R	Yes	Call TI   Sn	Level-1-260C-UNLIM	-40 to 125	1MG
TPS62A06DRLR.A	Active	Production	SOT-5X3 (DRL)   6	4000   LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	1MG

<sup>(1)</sup> Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

<sup>(2)</sup> Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

<sup>(4)</sup> Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

# **PACKAGE MATERIALS INFORMATION**

www.ti.com 25-Jul-2025

# TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

# QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS62A06ADRLR	SOT-5X3	DRL	6	4000	180.0	8.4	2.0	1.8	0.75	4.0	8.0	Q3
TPS62A06ADRLR	SOT-5X3	DRL	6	4000	180.0	8.4	1.8	1.8	0.75	4.0	8.0	Q3
TPS62A06DRLR	SOT-5X3	DRL	6	4000	180.0	8.4	1.8	1.8	0.75	4.0	8.0	Q3
TPS62A06DRLR	SOT-5X3	DRL	6	4000	180.0	8.4	2.0	1.8	0.75	4.0	8.0	Q3

www.ti.com 25-Jul-2025



# \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS62A06ADRLR	SOT-5X3	DRL	6	4000	210.0	185.0	35.0
TPS62A06ADRLR	SOT-5X3	DRL	6	4000	210.0	185.0	35.0
TPS62A06DRLR	SOT-5X3	DRL	6	4000	210.0	185.0	35.0
TPS62A06DRLR	SOT-5X3	DRL	6	4000	210.0	185.0	35.0



PLASTIC SMALL OUTLINE



#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
  4. Reference JEDEC registration MO-293 Variation UAAD



PLASTIC SMALL OUTLINE



NOTES: (continued)

- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.7. Land pattern design aligns to IPC-610, Bottom Termination Component (BTC) solder joint inspection criteria.



PLASTIC SMALL OUTLINE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



# IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATASHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you fully indemnify TI and its representatives against any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale, TI's General Quality Guidelines, or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products. Unless TI explicitly designates a product as custom or customer-specified, TI products are standard, catalog, general purpose devices.

TI objects to and rejects any additional or different terms you may propose.

Copyright © 2025, Texas Instruments Incorporated

Last updated 10/2025